

## Lecture 7

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### OUTLINE

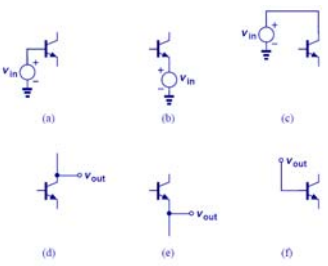
- Bipolar Amplifier Topologies (1)
  - Common-Emitter Amplifiers

Reading: Chapter 5.3.1

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## Possible Bipolar Amplifier Topologies

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- Three possible ways to apply an input to an amplifier and three possible ways to sense its output.
- However, in reality only three of six input/output combinations are useful.

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## Study of Common-Emitter Topology

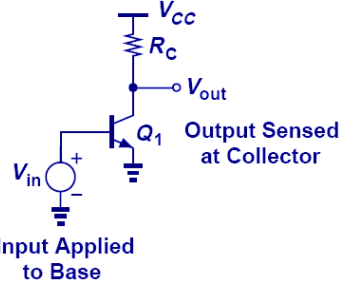
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- Analysis of CE Core
  - Inclusion of Early Effect
- Emitter Degeneration
  - Inclusion of Early Effect
- CE Stage with Biasing

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## Common-Emitter Topology

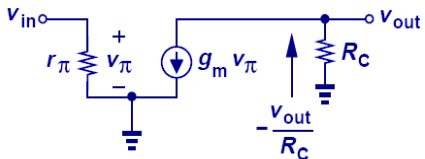
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## Small Signal of CE Amplifier

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$$A_v = \frac{v_{out}}{v_{in}}$$

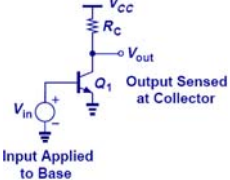
$$-\frac{v_{out}}{R_C} = g_m v_{\pi} = g_m v_{in}$$

$$A_v = -g_m R_C$$

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## Limitation on CE Voltage Gain

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$$|A_v| = \frac{I_C R_C}{V_T}$$

$$|A_v| = \frac{V_{RC}}{V_T}$$

$$|A_v| < \frac{V_{CC} - V_{BE}}{V_T}$$

- Since  $g_m$  can be written as  $I_C/V_T$ , the CE voltage gain can be written as the ratio of  $V_{RC}$  and  $V_T$ .
- $V_{RC}$  is the potential difference between  $V_{CC}$  and  $V_{CE}$ , and  $V_{CE}$  cannot go below  $V_{BE}$  in order for the transistor to be in active region.

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### Tradeoff between Voltage Gain and Headroom

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### I/O Impedances of CE Stage

$$R_{in} = \frac{v_x}{i_x} = r_{\pi}$$

$$R_{out} = \frac{v_x}{i_x} = R_C$$

- When measuring output impedance, the input port has to be grounded so that  $V_{in} = 0$ .

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### CE Stage Trade-offs

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### Inclusion of Early Effect

$$A_v = -g_m (R_C \parallel r_o)$$

$$R_{out} = R_C \parallel r_o$$

- Early effect will lower the gain of the CE amplifier, as it appears in parallel with  $R_C$ .

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### Intrinsic Gain

$$A_v = -g_m r_o$$

$$|A_v| = \frac{V_A}{V_T}$$

- As  $R_C$  goes to infinity, the voltage gain reaches the product of  $g_m$  and  $r_o$ , which represents the maximum voltage gain the amplifier can have.
- The intrinsic gain is independent of the bias current.

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### Current Gain

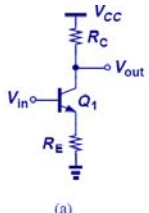
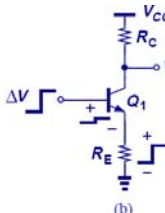
$$A_I = \frac{i_{out}}{i_{in}}$$

$$A_I|_{CE} = \beta$$

- Another parameter of the amplifier is the current gain, which is defined as the ratio of current delivered to the load to the current flowing into the input.
- For a CE stage, it is equal to  $\beta$ .

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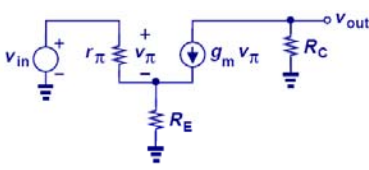
### Emitter Degeneration

- By inserting a resistor in series with the emitter, we "degenerate" the CE stage.
- This topology will decrease the gain of the amplifier but improve other aspects, such as linearity, and input impedance.

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### Small-Signal Model



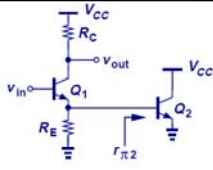
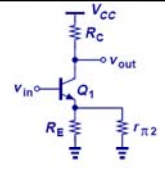
$$A_v = -\frac{g_m R_C}{1 + g_m R_E}$$

$$A_v = -\frac{R_C}{\frac{1}{g_m} + R_E}$$

- Interestingly, this gain is equal to the total load resistance to ground divided by  $1/g_m$  plus the total resistance placed in series with the emitter.

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### Emitter Degeneration Example I

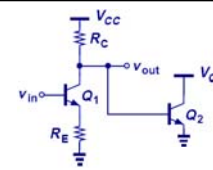
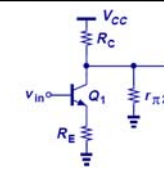



$$A_v = -\frac{R_C}{\frac{1}{g_{m1}} + R_E \parallel r_{\pi 2}}$$

- The input impedance of  $Q_2$  can be combined in parallel with  $R_E$  to yield an equivalent impedance that degenerates  $Q_1$ .

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### Emitter Degeneration Example II

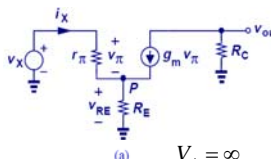
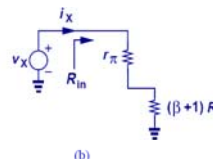



$$A_v = -\frac{R_C \parallel r_{\pi 2}}{\frac{1}{g_{m1}} + R_E}$$

- In this example, the input impedance of  $Q_2$  can be combined in parallel with  $R_C$  to yield an equivalent collector impedance to ground.

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### Input Impedance of Degenerated CE Stage

$$V_A = \infty$$

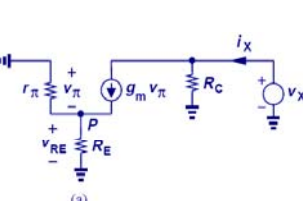
$$v_X = r_{\pi} i_X + R_E (1 + \beta) i_X$$

$$R_{in} = \frac{v_X}{i_X} = r_{\pi} + (\beta + 1) R_E$$

- With emitter degeneration, the input impedance is increased from  $r_{\pi}$  to  $r_{\pi} + (\beta + 1) R_E$ ; a desirable effect.

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### Output Impedance of Degenerated CE Stage without Considering Early Effect



$$V_A = \infty$$

$$v_{in} = 0 = v_{\pi} + \left( \frac{v_{\pi}}{r_{\pi}} + g_m v_{\pi} \right) R_E$$

$$\Rightarrow v_{\pi} = 0$$

$$R_{out} = \frac{v_X}{i_X} = R_C$$

- Emitter degeneration does not alter the output impedance in this case. (More on this later.)

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### Capacitor at Emitter

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$V_{CC}$   
 $R_C$   
 $V_{out}$   
 $Q_1$   
 $V_{in}$   
 $R_E$   
 Constant  
 $C_1$

- At DC the capacitor is open and the current source biases the amplifier.
- For ac signals, the capacitor is short and the amplifier is degenerated by  $R_E$ .

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### Example: Design CE Stage with Degeneration as a Black Box

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(a)  $V_A = \infty$       (b)

$$i_{out} = g_m \frac{v_{in}}{1 + (r_{\pi}^{-1} + g_m)R_E}$$

$$G_m = \frac{i_{out}}{v_{in}} \approx \frac{g_m}{1 + g_m R_E}$$

- If  $g_m R_E$  is much greater than unity,  $G_m$  is more linear.

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